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## NCE0240F

## NCE N-Channel Enhancement Mode Power MOSFET

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#### **Description**

The NCE0240F uses advanced trench technology and design to provide excellent RDS(ON) with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

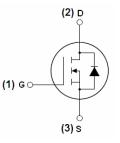
- V<sub>DS</sub> =200V,I<sub>D</sub> =40A  $R_{DS(ON)}$  <41m $\Omega$  @  $V_{GS}$ =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



#### Schematic diagram



#### Marking and pin assignment



TO-220F top view

**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0240F	NCE0240F	TO-220F	-	-	-

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	$V_{GS}$	±20	V
Drain Current-Continuous	I <sub>D</sub>	40	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100°C)	28	Α
Pulsed Drain Current	I <sub>DM</sub>	160	Α
Maximum Power Dissipation	P <sub>D</sub>	60	W
Derating factor		0.4	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	480	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	$^{\circ}$

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# NCE0240F

#### **Thermal Characteristic**

## Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>		•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3.2	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	36.4	41	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =25V,I <sub>D</sub> =25A	26	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ OF\/\/ O\/	-	6500	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,	-	290	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	220	-	PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>		-	26	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_D$ =2A, $R_L$ =15 $\Omega$	-	24	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =2.5 $\Omega$	-	91	-	nS
Turn-Off Fall Time	t <sub>f</sub>	V GS = 10 V , N G = 2.012		39	-	nS
Total Gate Charge	Qg	V -20V I -20A	-	163		nC
Gate-Source Charge	Qgs	V <sub>DS</sub> =30V,I <sub>D</sub> =30A,		31		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	64		nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	40	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 40A	-	42		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$ - 66			nC	
		Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

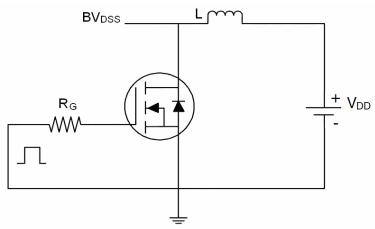
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E<sub>AS</sub> condition: Tj=25  $^{\circ}\text{C}$  ,V<sub>DD</sub>=50V,V<sub>G</sub>=10V,L=1mH,Rg=25 $\Omega$

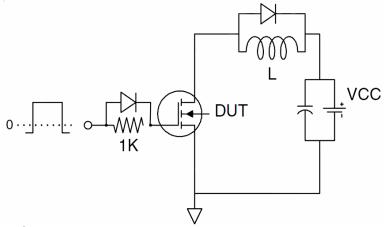


## **Test Circuit**

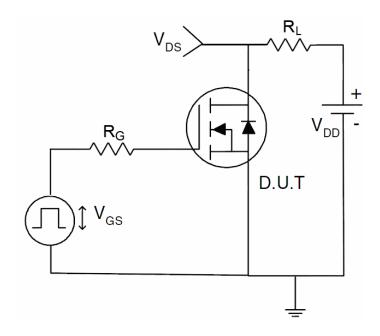
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

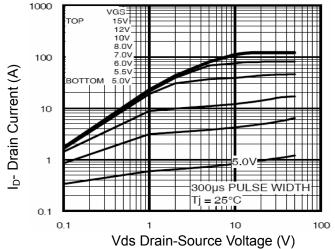


## 3) Switch Time Test Circuit

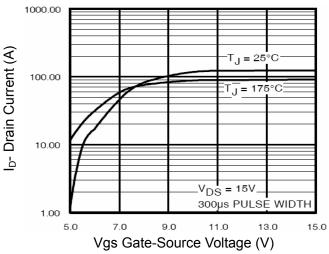








**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

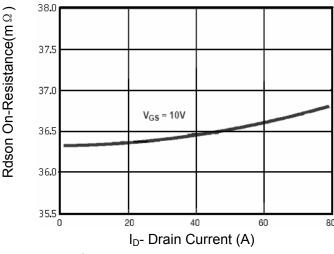


Figure 3 Rdson- Drain Current

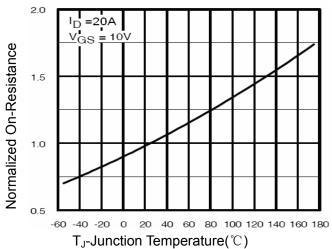
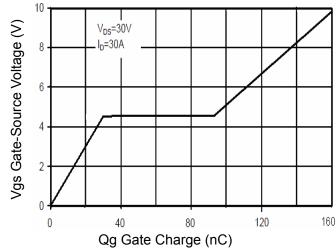


Figure 4 Rdson-JunctionTemperature



**Figure 5 Gate Charge** 

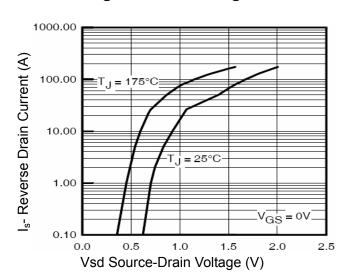


Figure 6 Source- Drain Diode Forward



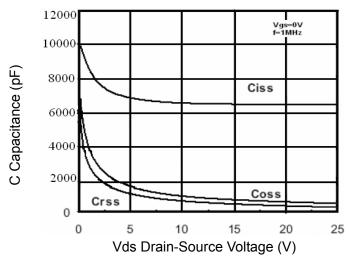


Figure 7 Capacitance vs Vds

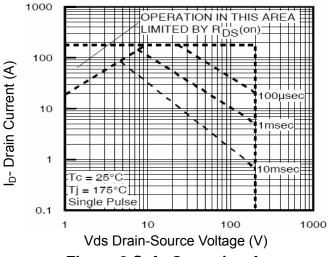


Figure 8 Safe Operation Area

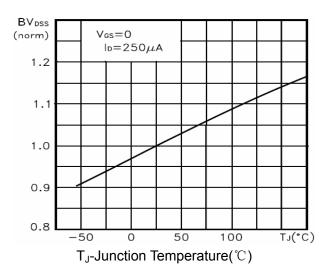


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

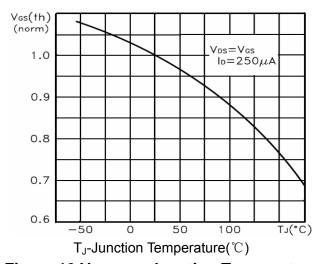


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

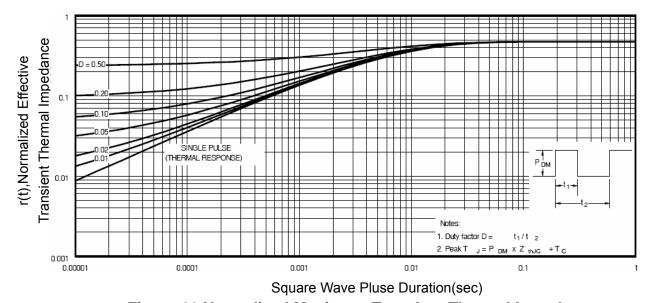
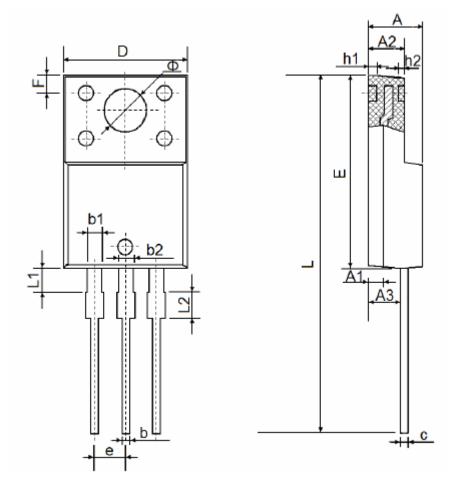


Figure 11 Normalized Maximum Transient Thermal Impedance

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## **TO-220F Package Information**



Oh al	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.300	4.700	0.169	0.185	
A1	1.300	DREF	0.051REF		
A2	2.800	3.200	0.110	0.126	
A3	2.500	2.900	0.098	0.114	
b	0.500	0.750	0.020	0.030	
b1	1.100	1.350	0.043	0.053	
b2	1.500	1.750	0.059	0.069	
С	0.500	0.750	0.020	0.030	
D	9.960	10.360	0.392	0.408	
E	14.800	15.200	0.583	0.598	
е	2.540TYP.		0.100TYP		
F	2.700REF		0.106REF		
Φ	3.500REF		0.138REF		
h1	0.800REF		0.031REF		
h2	0.500REF		0.020REF		
L	28.000	28.400	1.102	1.118	
L1	1.700	1.900	0.067	0.075	
L2	1.900	2.100	0.075	0.083	



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